





#### **50V NPN SURFACE MOUNT TRANSISTOR IN SOT89**

#### **Features**

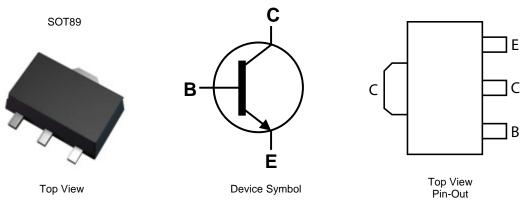
- BV<sub>CEO</sub> > 50V
- I<sub>C</sub> = 3A High Continuous Current
- Low saturation voltage  $V_{CE(sat)}$  < 350mV @ 1A
- Complementary PNP type: 2DA1797
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.052 grams (Approximate)

## **Applications**

- Load Management Functions
- Solenoid, Relay and Actuator Drivers
- DC DC Modules



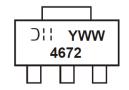
## Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
2DC4672-13	4672	13	12	2,500
2DC4672-13R	4672	13	12	4,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html

## **Marking Information**



4672 = Product Type Marking Code YWW = Date Code Marking Y = Last digit of year (ex: 8 = 2008)WW = Week code 01 - 53

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## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	$V_{CEO}$	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	I <sub>C</sub>	3	Α
Peak Pulse Current	I <sub>CM</sub>	6	Α
Base Current	I <sub>B</sub>	500	mA

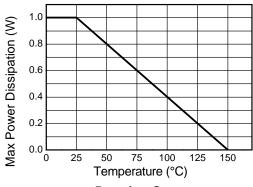
### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	Б	1	W	
Power Dissipation	(Note 6)	$P_{D}$	2	]	
Thermal Desistance, Junction to Ambient Air	(Note 5)	<u> </u>	125	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{\theta JA}$	62.5		
Thermal Resistance, Junction to Leads	(Note 7)	R <sub>0JL</sub>	5.73	°C/W	
Operating and Storage Temperature Range		$T_J,T_STG$	-55 to +150	°C	

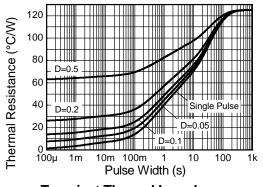
Notes:

- 5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.
- measured when operating in steady state condition.
  6. Same as note (5), except the device is mounted on 40mm x 40mm x 1.6mm FR4 PCB
- 7. Thermal resistance from junction to solder-point (on the exposed collector pad).

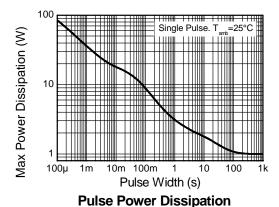
## **Thermal Characteristics and Derating Information**







**Transient Thermal Impedance** 



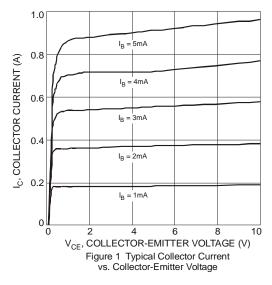


## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	60	_	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	$BV_CEO$	50	_	_	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	_		V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CBO</sub>	_	_	100	nA	V <sub>CB</sub> = 60V
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	100	nA	$V_{EB} = 5.6V$
DC Current Transfer Static Ratio (Note 8)	h <sub>FE</sub>	82 45	_	270 —	_	$I_C = 500$ mA, $V_{CE} = 2V$ $I_C = 1.5$ A, $V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(sat)</sub>	_	105	350	mV	$I_C = 1A, I_B = 50mA$
Transitional Frequency	f⊤	_	180	_	MHz	$I_C = 100$ mA, $V_{CE} = 2V$ f = 1MHz
Output Capacitance	C <sub>obo</sub>	_	17	_	pF	V <sub>CB</sub> = 10V, f = 1MHz,

Note:

### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



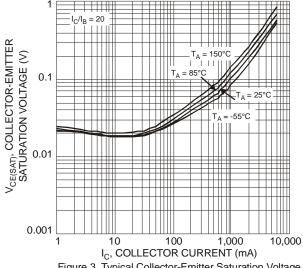


Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

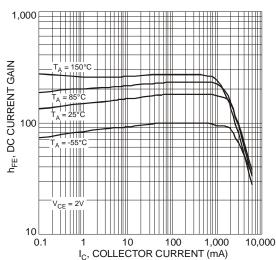


Figure 2 Typical DC Current Gain vs. Collector Current

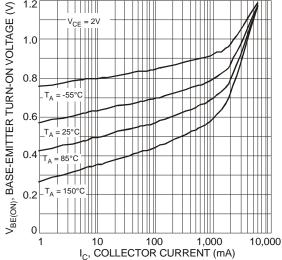


Figure 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

<sup>8.</sup> Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



## **Typical Electrical Characteristics** (cont.)

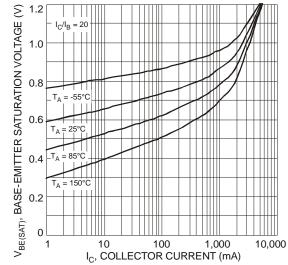
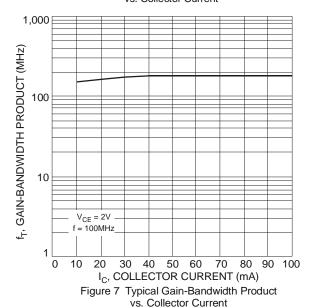


Figure 5 Typical Base-Emitter Saturation Voltage vs. Collector Current



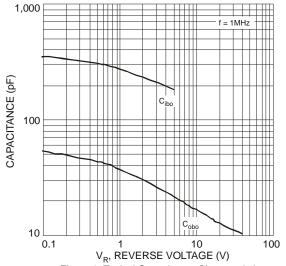


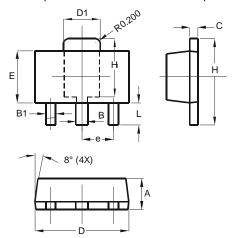
Figure 6 Typical Capacitance Characteristics





# **Package Outline Dimensions**

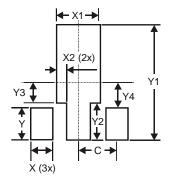
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
E	2.29	2.60		
е	1.50 Typ			
Н	3.94	4.25		
H1	2.63	2.93		
L	0.89	1.20		
All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500

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